



High Intensity LED in ∅ 3 mm Clear Package

Description

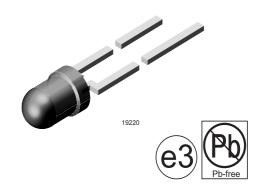
This LED contains the double heterojunction (DH) GaAlAs on GaAs technology.

This deep red LED can be utilized over a wide range of drive current. It can be DC or pulse driven to achieve desired light output.

The device is available in a clear 3 mm package.

Features

- · Exceptional brightness
- · Very high intensity even at low drive currents
- · Small viewing angle
- · Low forward voltage
- 3 mm (T-1) untinted non-diffused package
- · Deep red color
- · Categorized for luminous intensity
- · Outstanding material efficiency
- · Lead-free device



Applications

Bright ambient lighting conditions Battery powered equipment Indoor and outdoor information displays Portable equipment Telecommunication indicators General use

Parts Table

| Part | Color, Luminous Intensity | Angle of Half Intensity (±φ) | Technology |
|----------|---------------------------------------|------------------------------|----------------|
| TLDR4900 | Red, I _V > 63 mcd | 16 ° | GaAlAs on GaAs |
| TLDR4901 | Red, I _V = (63 to 200) mcd | 16 ° | GaAlAs on GaAs |

Absolute Maximum Ratings

 $T_{amb} = 25$ °C, unless otherwise specified

| Parameter | Test condition | Symbol | Value | Unit |
|--------------------------------------|-----------------------------|-------------------|---------------|------|
| Reverse voltage | | V _R | 6 | V |
| DC Forward current | | I _F | 50 | mA |
| Surge forward current | t _p ≤ 10 μs | I _{FSM} | 1 | А |
| Power dissipation | T _{amb} ≤ 60 °C | P _V | 100 | mW |
| Junction temperature | | T _j | 100 | °C |
| Operating temperature range | | T _{amb} | - 40 to + 100 | °C |
| Storage temperature range | | T _{stg} | - 55 to + 100 | °C |
| Soldering temperature | $t \le 5$ s, 2 mm from body | T _{sd} | 260 | °C |
| Thermal resistance junction/ ambient | | R _{thJA} | 400 | K/W |

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Optical and Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Red

TLDR490.

| Parameter | Test condition | Part | Symbol | Min | Тур. | Max | Unit |
|--------------------------|-------------------------------|----------|----------------|-----|------|-----|------|
| Luminous intensity 1) | I _F = 20 mA | TLDR4900 | I _V | 63 | 200 | | mcd |
| | | TLDR4901 | I _V | 63 | | 200 | mcd |
| Luminous intensity | I _F = 1 mA | | I _V | | 8 | | mcd |
| Dominant wavelength | I _F = 20 mA | | λ_{d} | | 648 | | nm |
| Peak wavelength | I _F = 20 mA | | λ_{p} | | 650 | | nm |
| Spectral line half width | I _F = 20 mA | | Δλ | | 20 | | nm |
| Angle of half intensity | I _F = 20 mA | | φ | | ± 16 | | deg |
| Forward voltage | I _F = 20 mA | | V _F | | 1.8 | 2.2 | V |
| Reverse current | V _R = 6 V | | I _R | | | 10 | μΑ |
| Junction capacitance | V _R = 0, f = 1 MHz | | C _j | | 30 | | pF |

 $[\]overline{\ \ \ \ \ \ \ \ }$ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

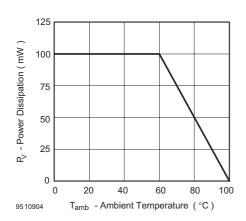


Figure 1. Power Dissipation vs. Ambient Temperature

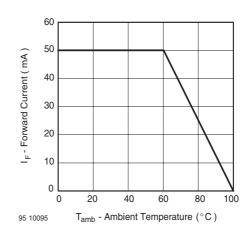


Figure 2. Forward Current vs. Ambient Temperature for InGaN



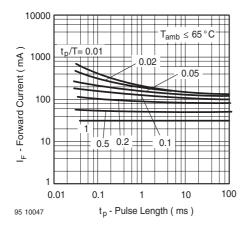


Figure 3. Forward Current vs. Pulse Length

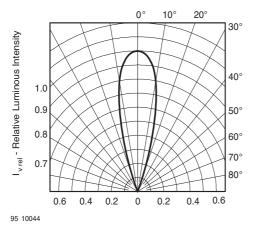


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

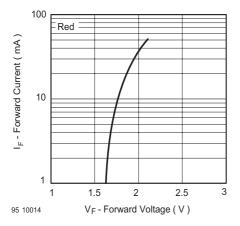


Figure 5.

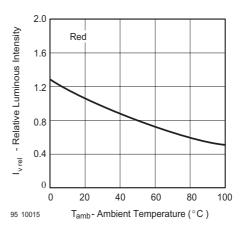


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

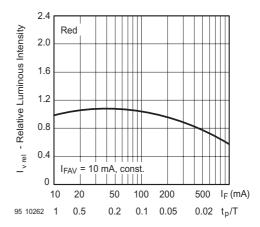


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

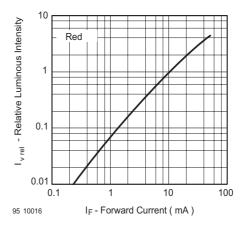


Figure 8. Relative Luminous Intensity vs. Forward Current



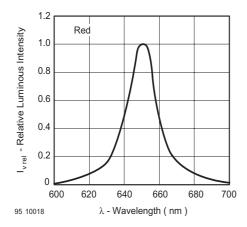
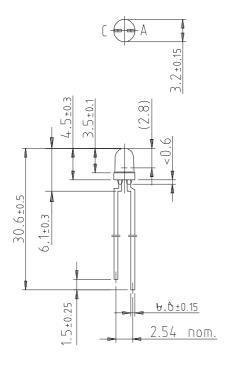
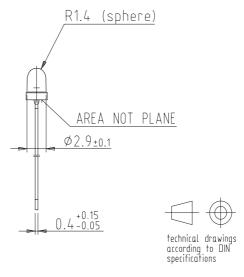


Figure 9. Relative Intensity vs. Wavelength

Package Dimensions in mm





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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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